



**IXYS**  
A Littelfuse Technology

Date:- 12 May, 2022

Data Sheet Issue:- A1

Advance data

# Insulated Gate Bi-Polar Transistor Type T0710TC33A

## Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V <sub>CES</sub>	Collector – emitter voltage	3300	V
V <sub>DC link</sub>	Permanent DC voltage for 100 FIT failure rate.	1800	V
V <sub>GES</sub>	Peak gate – emitter voltage	±20	V

	RATINGS	MAXIMUM LIMITS	UNITS
I <sub>C(DC)</sub>	DC collector current, IGBT	710	A
I <sub>CRM</sub>	Repetitive peak collector current, t <sub>p</sub> =1ms, IGBT	1420	A
I <sub>F(DC)</sub>	Continuous DC forward current, Diode	710	A
I <sub>FRM</sub>	Repetitive peak forward current, t <sub>p</sub> =1ms, Diode	1420	A
I <sub>FSM</sub>	Peak non-repetitive surge t <sub>p</sub> =10ms, V <sub>RM</sub> =60%V <sub>RRM</sub> , Diode (Note 4)	3736	A
I <sub>FSM2</sub>	Peak non-repetitive surge t <sub>p</sub> =10ms, V <sub>RM</sub> ≤10V, Diode (Note 4)	4110	A
P <sub>MAX</sub>	Maximum power dissipation, IGBT (Note 2)	4.59	kW
P <sub>D</sub>	Maximum power dissipation, Diode (Note 2)	2.31	kW
(di/dt) <sub>cr</sub>	Critical diode di/dt (note 3)	1500	A/μs
T <sub>j</sub>	Operating temperature range.	-40 to +125	°C
T <sub>stg</sub>	Storage temperature range.	-40 to +125	°C

Notes: -

- 1) Unless otherwise indicated T<sub>j</sub> = 125°C.
- 2) T<sub>sink</sub> = 25°C, double side cooled.
- 3) Maximum commutation loop inductance 600nH.
- 4) Half-sinewave, 125°C T<sub>j</sub> initial.

## Characteristics

### IGBT Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
$V_{CE(sat)}$	Collector – emitter saturation voltage	-	2.55	2.85	$I_C = 710A, V_{GE} = 15V, T_j = 25^\circ C$	V
		-	3.30	3.60	$I_C = 710A, V_{GE} = 15V$	V
$V_{T0}$	Threshold voltage	-	-	1.71	Current range: 237 – 710A	V
$r_T$	Slope resistance	-	-	2.67		mΩ
$V_{GE(TH)}$	Gate threshold voltage	-	5.2	-	$V_{CE} = V_{GE}, I_C = 60mA$	V
$I_{CES}$	Collector – emitter cut-off current	-	4	18	$V_{CE} = V_{CES}, V_{GE} = 0V$	mA
$I_{GES}$	Gate leakage current	-	-	±10	$V_{GE} = \pm 20V$	μA
$C_{ies}$	Input capacitance	-	97	-	$V_{CE} = 25V, V_{GE} = 0V, f = 1MHz$	nF
$t_{d(on)}$	Turn-on delay time	-	1.4	-	$I_C = 710A, V_{CE} = 1800V, di/dt = 1400A/\mu s$	μs
$t_r(V)$	Rise time	-	1.6	-		μs
$Q_{g(on)}$	Turn-on gate charge	-	13.5	-	$V_{GE} = \pm 15V, L_s = 600nH$	μC
$E_{on}$	Turn-on energy	-	1.5	-	$R_{G(ON)} = 2.7\Omega, R_{G(OFF)} = 21\Omega, C_{GE} = 300nF$	J
$t_{d(off)}$	Turn-off delay time	-	5.1	-	Integral diode used as freewheel diode (Note 3, 4 & 5)	μs
$t_f(I)$	Fall time	-	1.3	-		μs
$Q_{g(off)}$	Turn-off gate charge	-	9	-		μC
$E_{off}$	Turn-off energy	-	2	-		J
$I_{SC}$	Short circuit current	-	2800	-	$V_{GE} = +15V, V_{CC} = 1800V, V_{CEmax} \leq V_{CES},$ $t_p \leq 10\mu s, L_s < 150nH$	A

### Diode Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
$V_F$	Forward voltage	-	2.95	3.25	$I_F = 710A, T_j = 25^\circ C$	V
		-	2.90	3.20	$I_F = 710A$	V
$V_{T0}$	Threshold voltage	-	-	1.61	Current range 237 - 710A	V
$r_T$	Slope resistance	-	-	2.24		mΩ
$I_{rm}$	Peak reverse recovery current	-	420	-	$I_F = 710A, V_r = 1800V, V_{GE} = -15V,$ $di/dt = 1400A/\mu s$	A
$Q_{rr}$	Recovered charge	-	570	-		μC
$t_{rr}$	Reverse recovery time, 50% chord	-	1.65	-		μs
$E_r$	Reverse recovery energy	-	0.6	-		J

### Thermal Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
$R_{thJK}$	Thermal resistance junction to sink, IGBT	-	-	21.8	Double side cooled	K/kW
		-	-	36.8	Collector side cooled	K/kW
		-	-	53.5	Emitter side cooled	K/kW
$R_{thJK}$	Thermal resistance junction to sink, Diode	-	-	43.2	Double side cooled	K/kW
		-	-	68	Cathode side cooled	K/kW
		-	-	118	Anode side cooled	K/kW
F	Mounting force	15	20	25	Note 2	kN
$W_t$	Weight	-	1.2	-		kg

#### Notes:-

- 1) Unless otherwise indicated  $T_j = 125^\circ C$ .
- 2) Consult application note 2008AN01 for detailed mounting requirements
- 3)  $C_{GE}$  is additional gate – emitter capacitance added to output of gate drive
- 4)  $E_{on}$  integration time 15μs from 10% rising  $I_G$ .
- 5)  $E_{off}$  integration time 15μs from 90% falling  $V_{GE}$ .

## Curves

Figure 1 – Typical collector-emitter saturation voltage characteristics

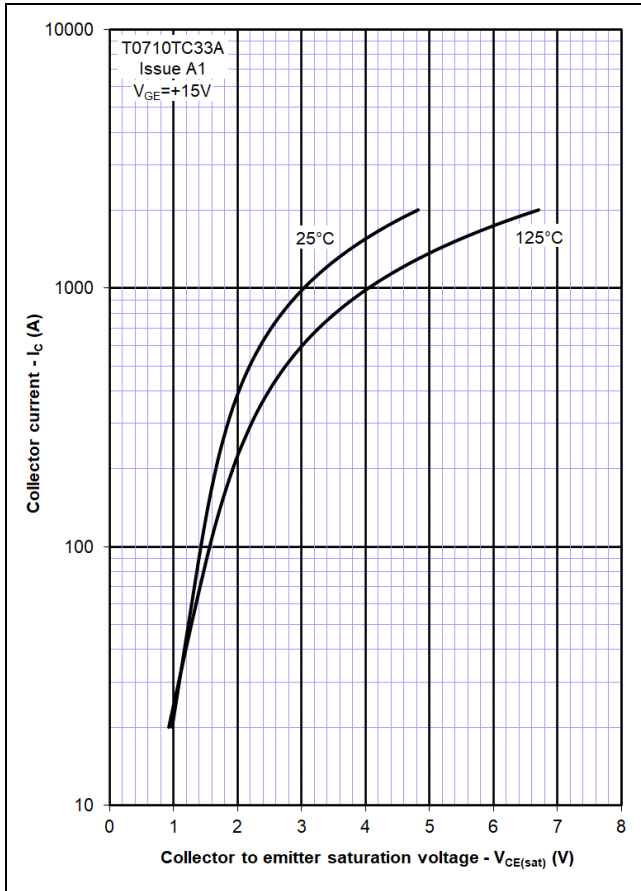


Figure 2 – Typical output characteristic

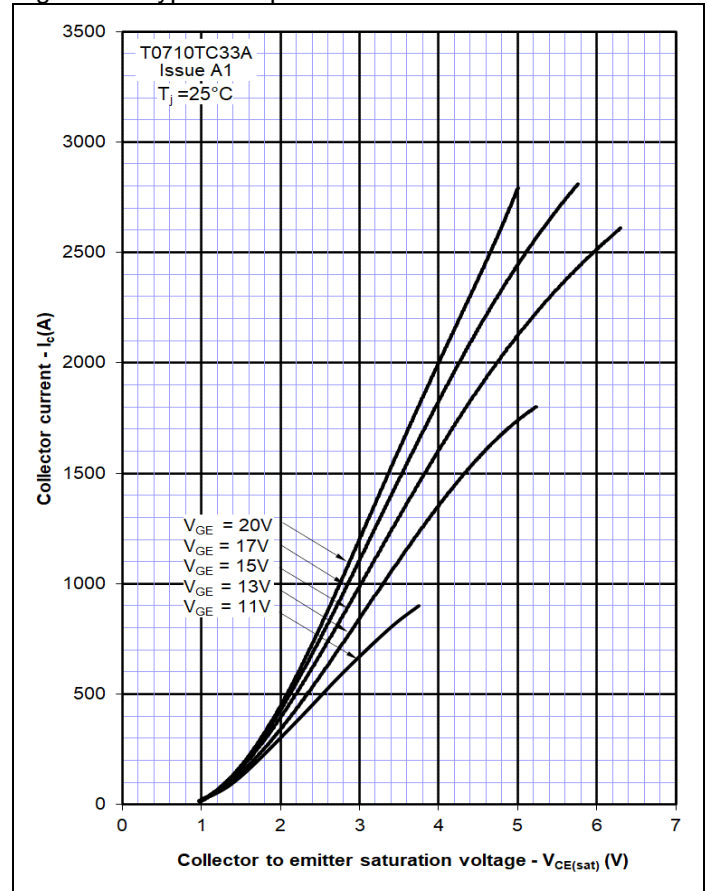


Figure 3 – Typical output characteristic

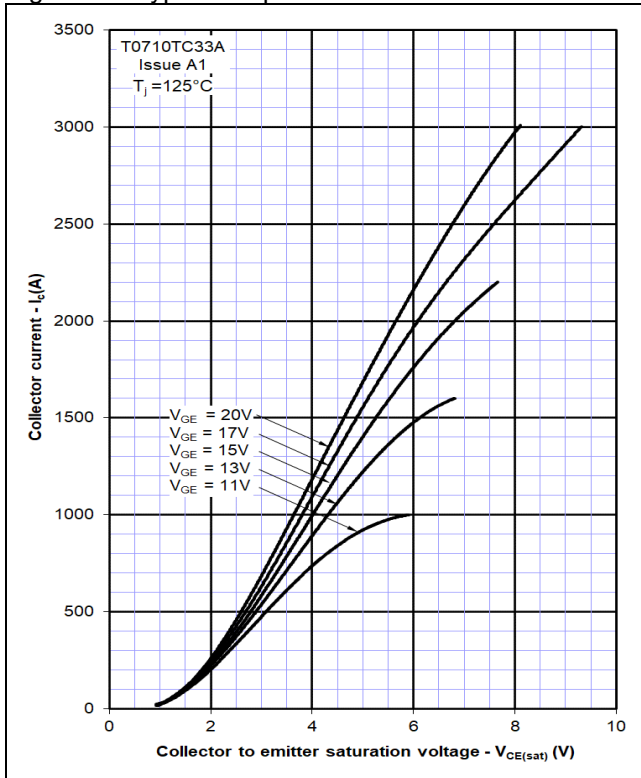


Figure 4 – Typical turn-on delay time vs gate resistance

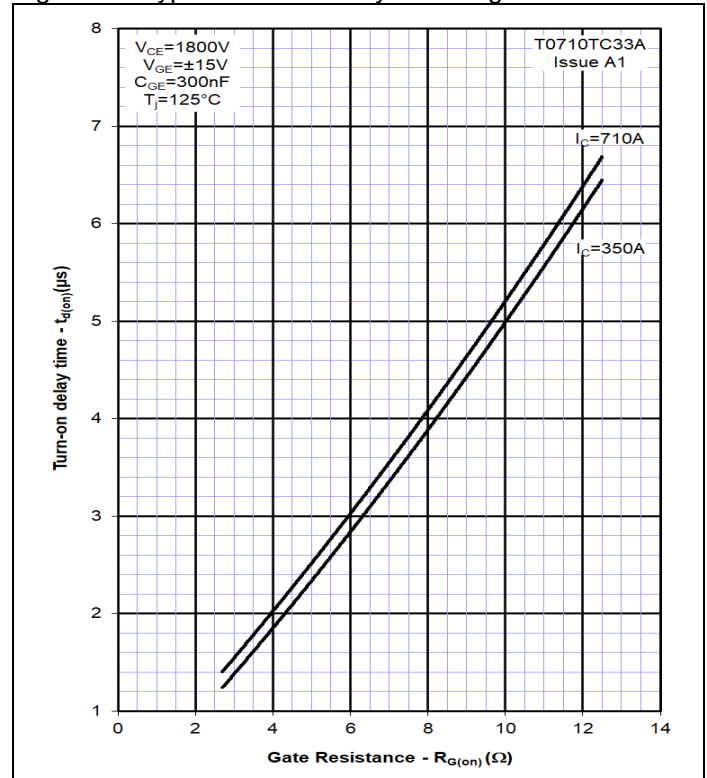


Figure 5 – Typical turn-off delay time vs. gate resistance

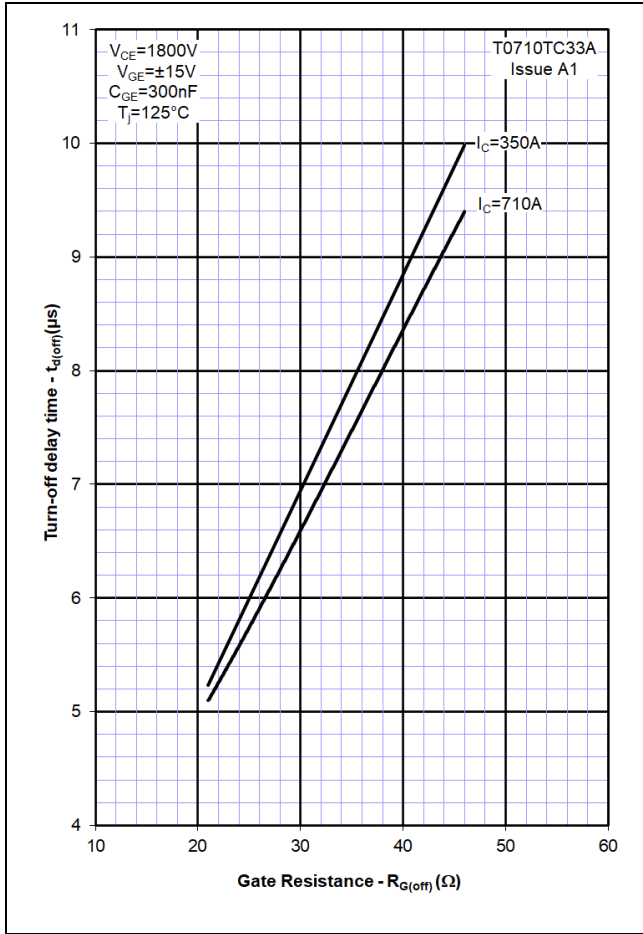


Figure 6 – Typical turn-on energy vs. collector current

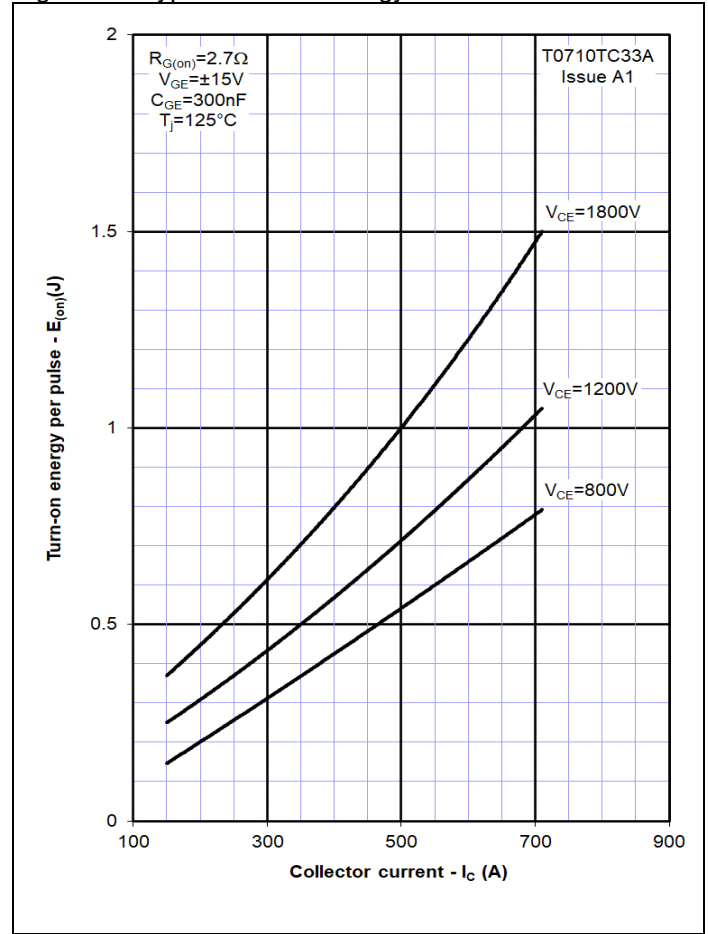


Figure 7 – Typical turn-on energy vs. di/dt

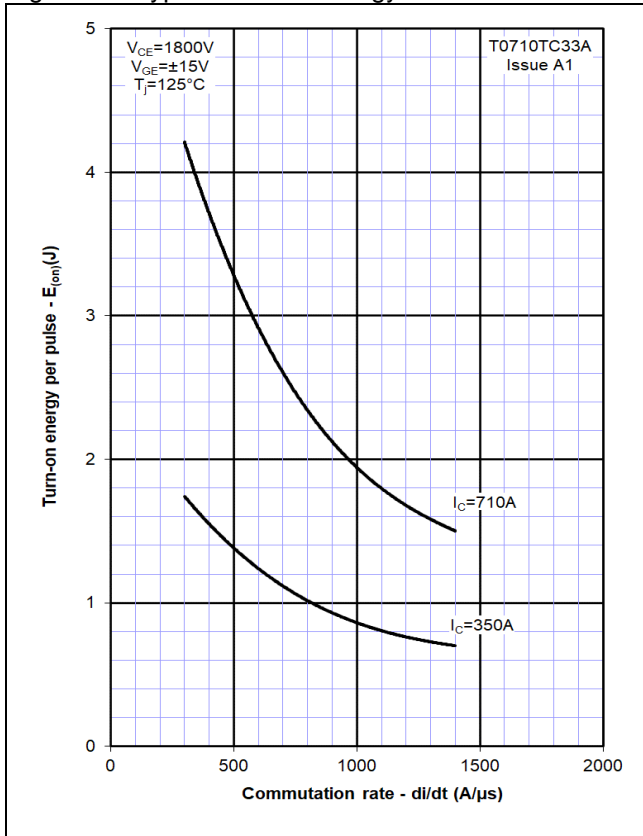


Figure 8 – Typical turn-off energy vs. collector current

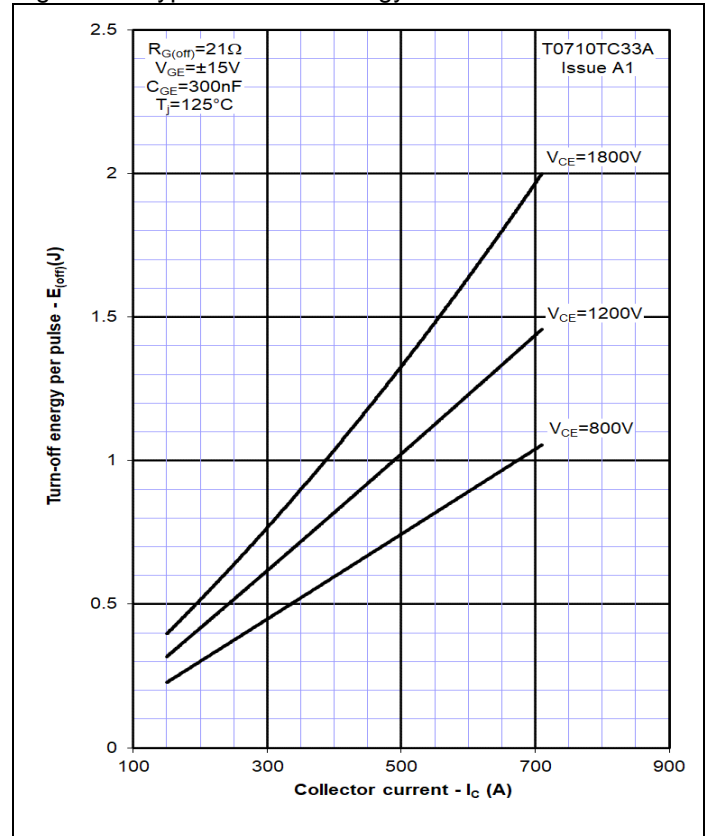


Figure 9 – Turn-off energy vs voltage

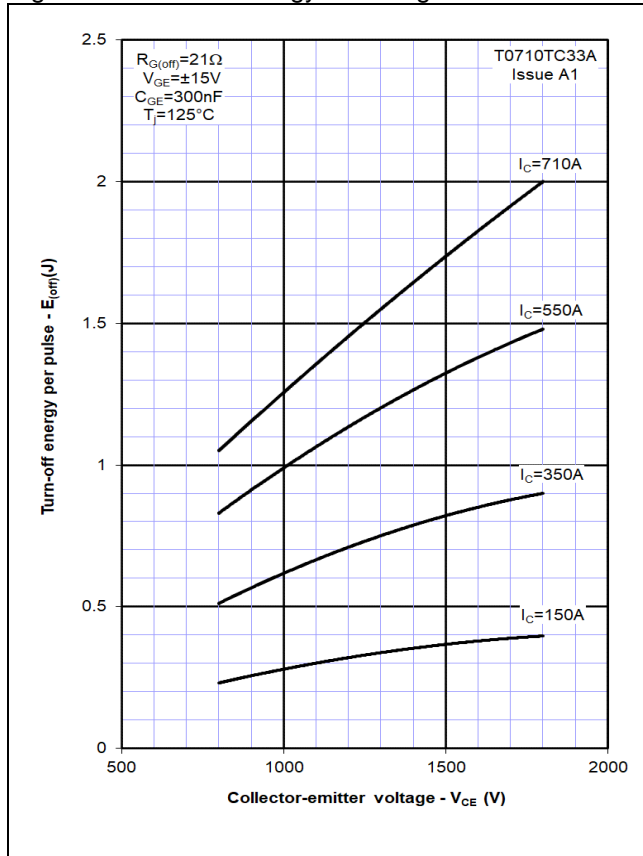


Figure 10 – Safe operating area (IGBT)

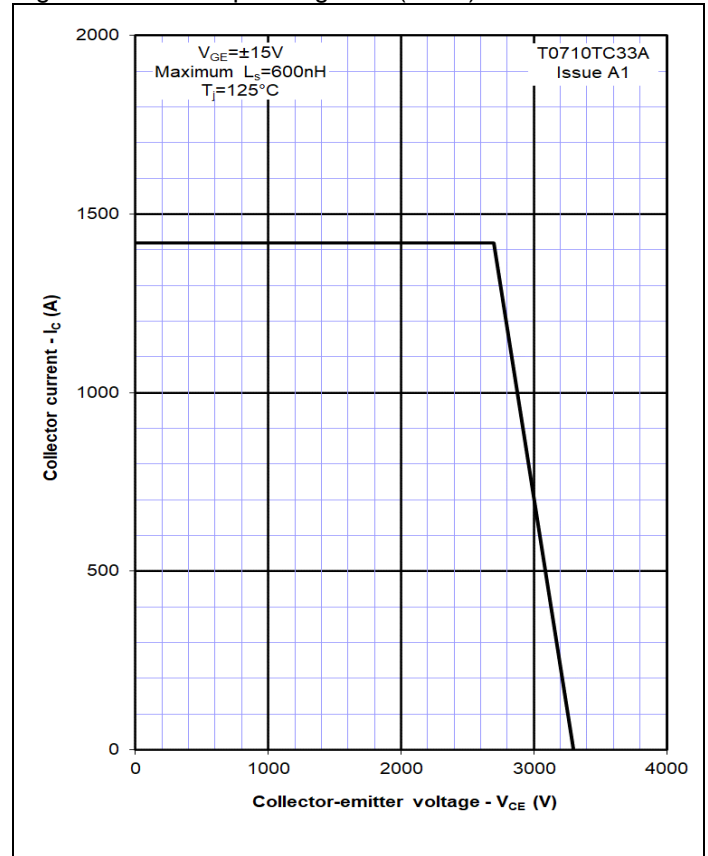


Figure 11 – Typical diode forward characteristics

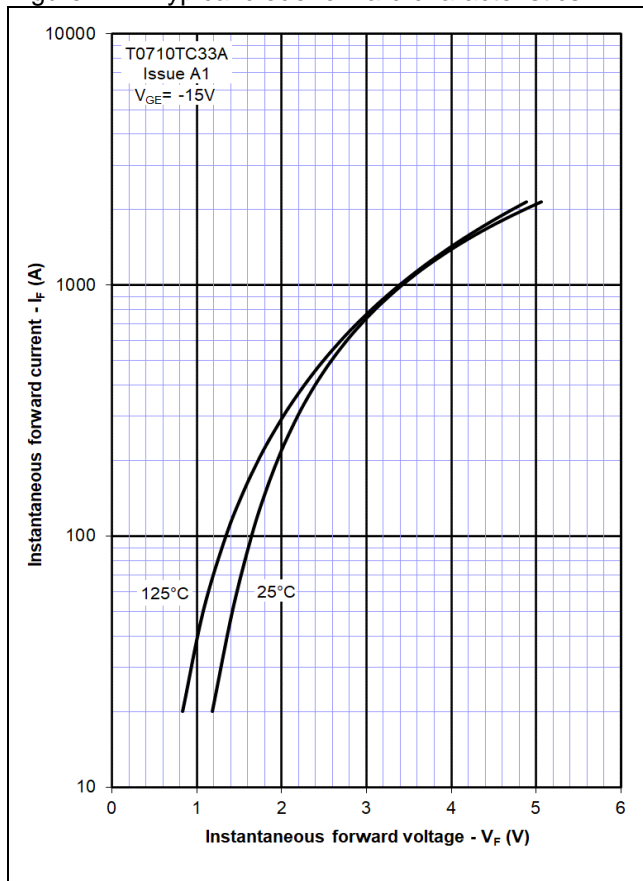


Figure 12 – Typical recovered charge

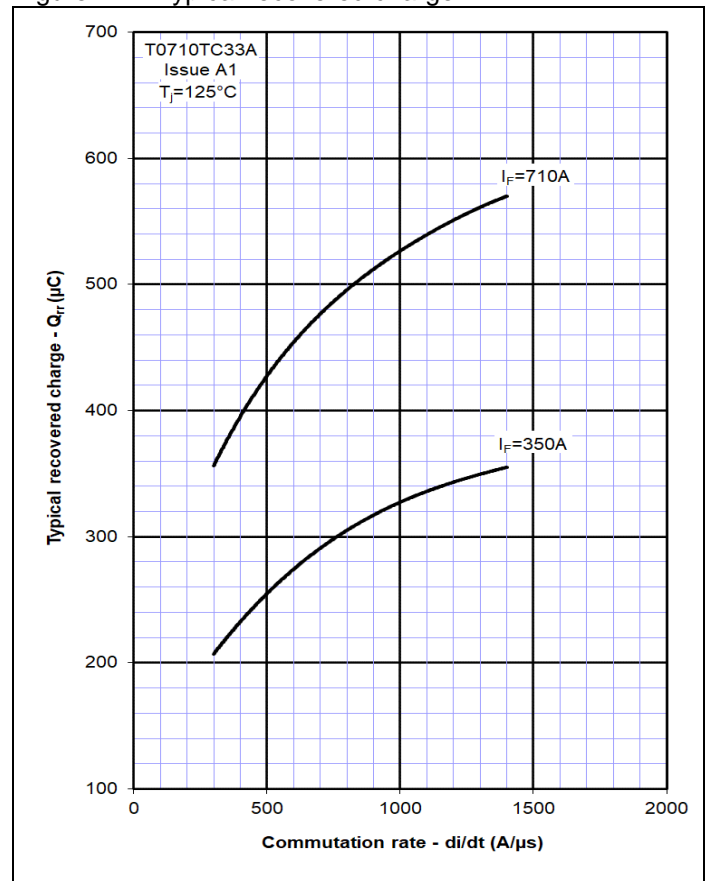


Figure 13 – Typical reverse recovery current

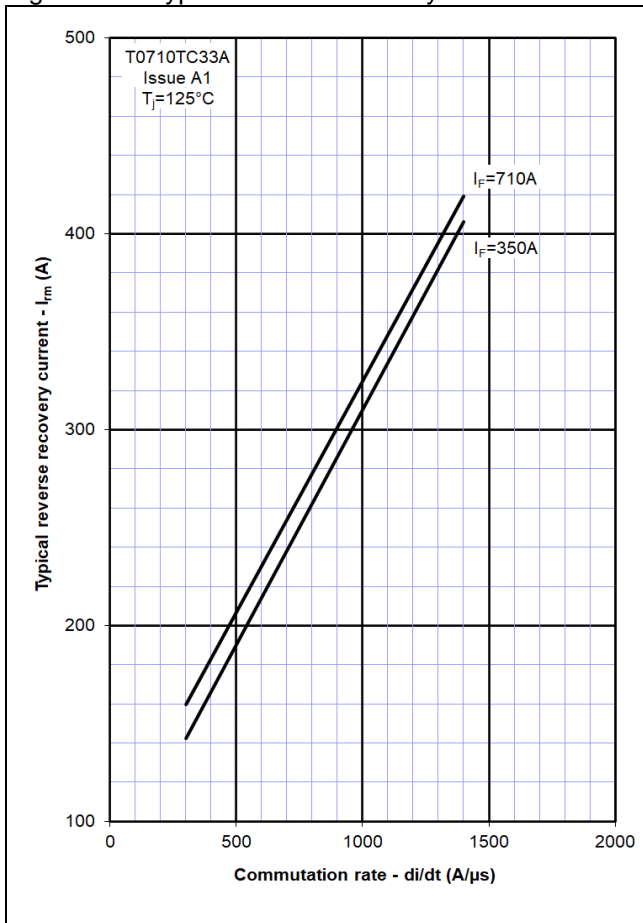


Figure 14 – Typical reverse recovery time

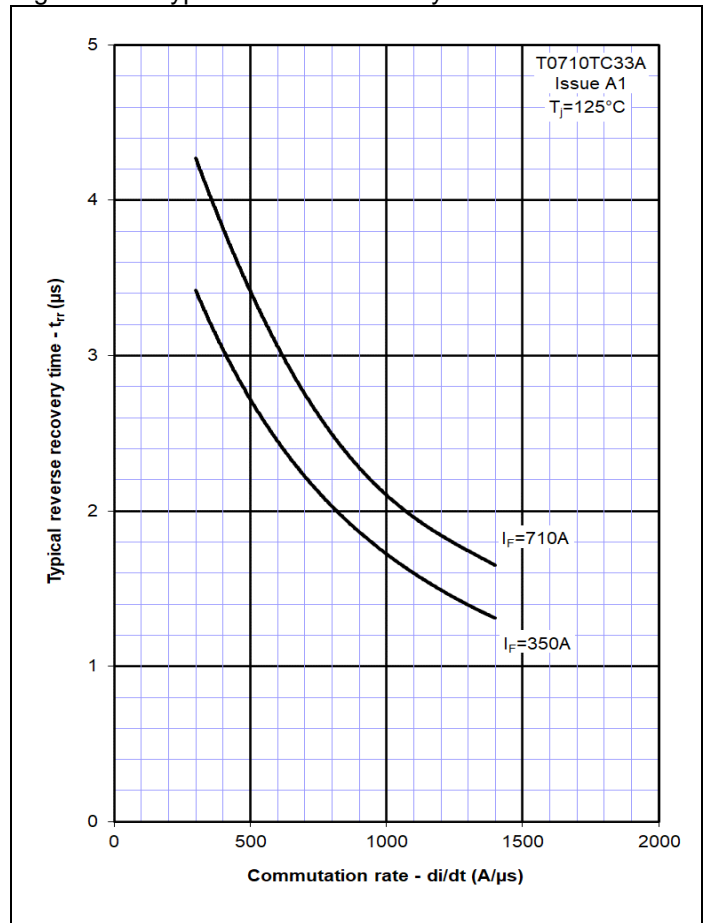


Figure 15 – Typical reverse recovery energy

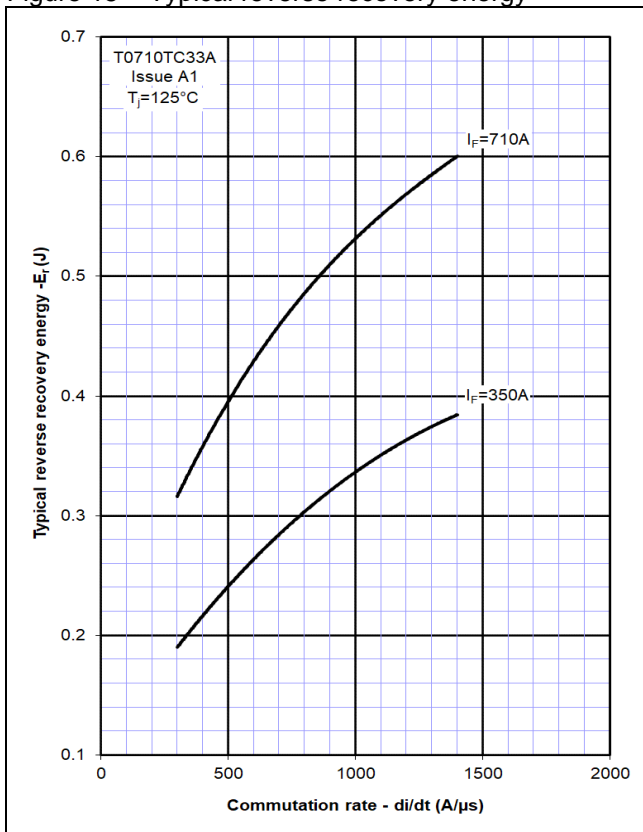


Figure 16 – Safe operating area (Diode)

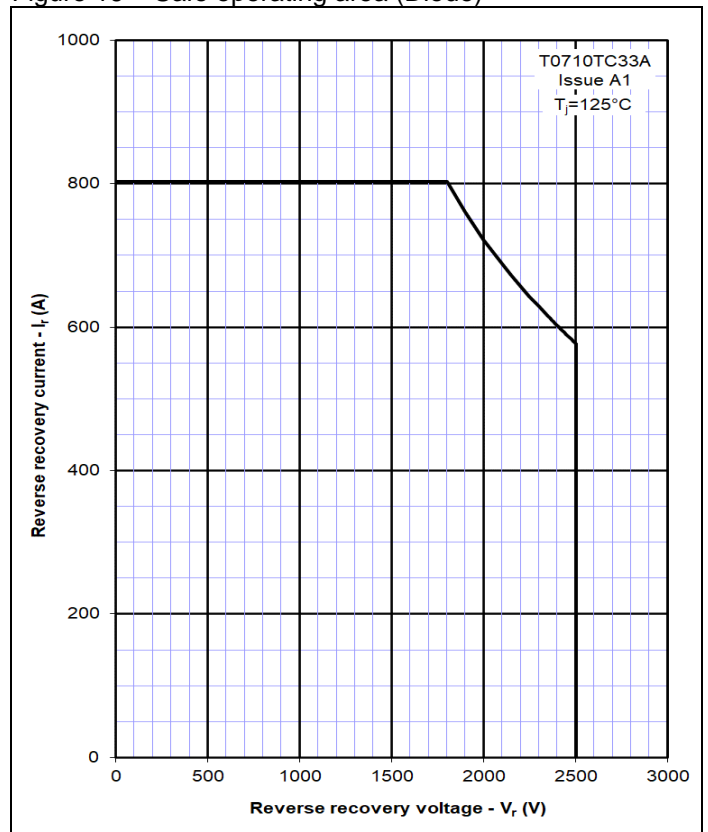


Figure 17 – Transient thermal impedance (IGBT)

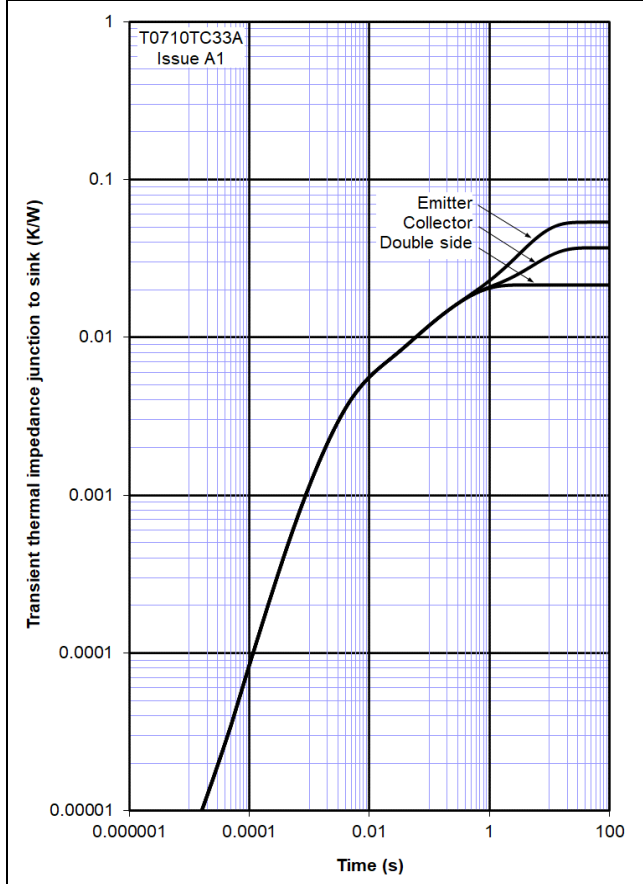
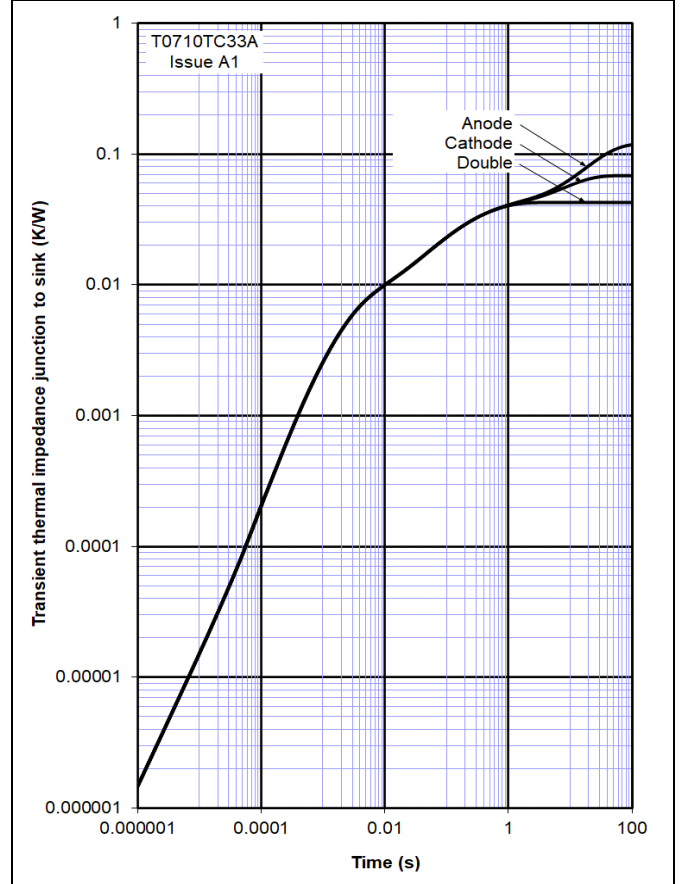
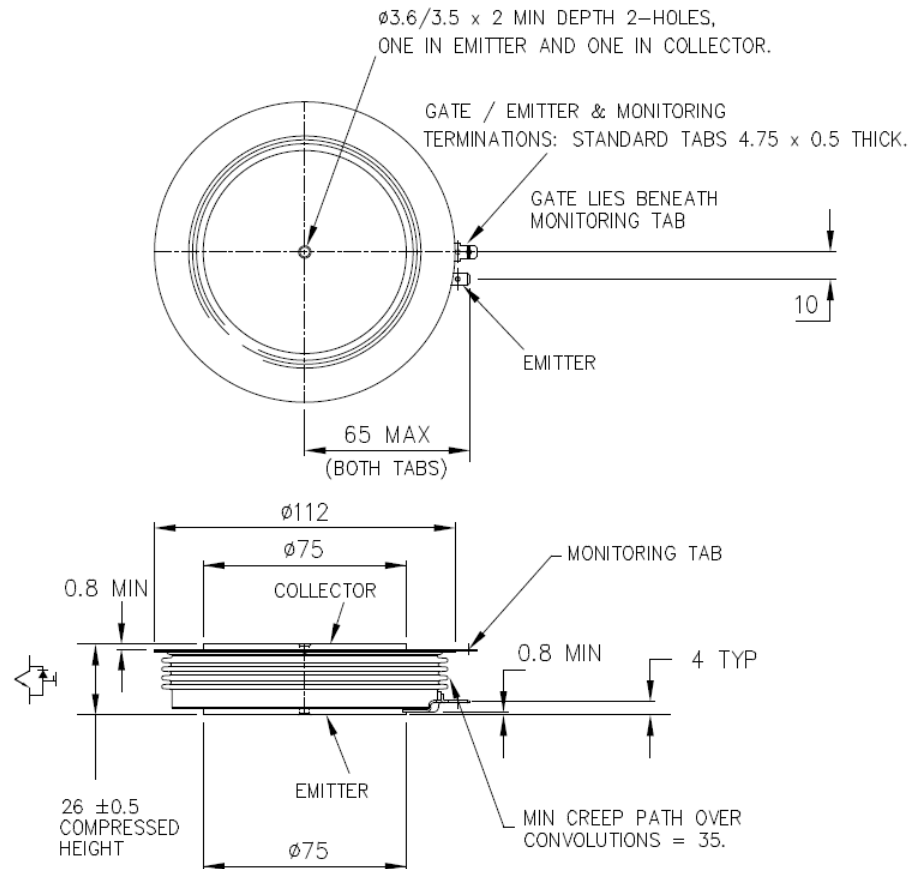


Figure 18 – Transient thermal impedance (Diode)



## Outline Drawing & Ordering Information



171A108

### ORDERING INFORMATION

(Please quote 10 digit code as below)

T0710	TC	33	A
Fixed type Code	Fixed Outline Code	Voltage Grade $V_{CES}/100$ 33	Fixed format code

 Typical order code: T0710TC33A ( $V_{CES} = 3300V$ )

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